### as a beam profile monitor



### Active Pixel Sensor

#### double layer of silicon disks

pixel size	100 x 100 μm <sup>2</sup>
thickness	300 µm
inner radius	2 cm
outer radius	8.5 cm
location (z)	176 and 177 cm from IP

Measurement:

position and energy deposit



80 cm  $\phi$  support tube



1/100 bunch and E\_{\gamma}>100MeV, E\_e>10MeV for display purpose

JIM simulation for  $E_{\gamma}$ >10keV,  $E_{e}$ >200keV

### Photon Background



#### Vertex detector hit density in stronger B fields

 $\cos\theta < 0.9$ 



# Summary of pair backgrounds

#### Blue numbers are those of JLC parameter-Y.

name	r	Z	B=2 Tesla	B=3 Tesla
	cm	cm	per 10 bunch	crossings*
no. of γ's	30.	±100	3076	371
			6082	946
hits:vtx-1	2.5	±7.5	2186,	900,
			0.9/mm <sup>2</sup> /train	0.4/mm <sup>2</sup> /train
			3279,	1205,
			2.8/mm <sup>2</sup> /train	1.0/mm <sup>2</sup> /train
vtx-2	5.0	±15.0	720	104
			920	306
vtx-3	7.5	±22.5	406	34
			545	138
CDC	45~230	±230	121 (101)	12 (9)
			235 (194)	37 (28)
			hit#(track#)	hit#(track#)

\* 190 bunches/train for Y while 95 bunches/train for A.

# Summary of pair backgrounds

Beam pipe with 1cm radius and Be-500  $\mu$ m thickness at IP

name	r	Z	B=2 Tesla	B=3 Tesla
	cm	cm	per 10 bunch	ncrossings
no. of γ's	30.	±100	11140	5857
				1626
hits:vtx-1	1.5	±4.5	10244,12/mm <sup>2</sup>	3065,3.6/mm <sup>2</sup>
	1.8	±5.4		1906,1.6/mm <sup>2</sup>
vtx-2	2.5	±7.5	1988	680
				804
vtx-3	5.0	±15.0	600	402
				208
CDC	45~230	±230	420(375)	259(217)
				72(63)
			hit#(track#)	hit#(track#)

Green numbers with 3cm beam pipe.

# Background tolerance (1) CDC 10 % occupancy / train

r <sub>min</sub> B	2 tesla	3 tesla
2.5 cm hit#/train	 1.2 k (2.4 k)	0.12 k (0.37 k)
1.8 cm		O <sub>0.72 k</sub>
1.5 cm hit#/train	۲.2 k	2.6 k

## (2) VTX 1hit / mm<sup>2</sup> / train

r <sub>min</sub> B	2 tesla	3 tesla
2.5 cm hit#/mm²/train	○	0.4 (1.0)
1.8 cm		<u> </u>
1.5 cm hit#/mm²/train	4.3	>> 3.6

Values in () are those of JLC-Y (high luminosity).

4,3 and  $2cm\phi$  beam pipes for  $r_{min}=2.5,1.8$  and 1.5 cm, respectively.

### **Magnetic field(Bz) distribution**

A.Miyamoto, LC99, Oct., 1999





#### A.Miyamoto, LC99, Oct., 1999



### A.Miyamoto, LC99, Oct., 1999 Summary of Neutron Background in VTX

Neutron yield at IP(/cm<sup>2</sup>/year)

e<sup>+</sup>e<sup>-</sup>: Old (GEANT)  $3x10^7$ New(Fluka98) w 2T solenoid  $5 x10^7$ 

New(Fluka98) w. CC and QC  $7 \times 10^7$ 

beamstrahlung:	Old(GEANT)	$1 \times 10^{7}$
from beam dump(340kW)	$\mathbf{N}_{avv}(\mathbf{\Gamma}_{1v}_{1v}_{av}, \mathbf{O}_{2v})$	$2.5 \times 10^7$
(300m from IP)	New(Fluka98)	$2.3 \times 10$

Statistical error of new estimate is roughly a few x 10<sup>'</sup> (guess)

New estimatebased on Fluka98 is well below the requirement,  $< 1.5 \times 10^{10} \text{ n/cm}^2$ for the CCD vertex detector

Neutron background from other sources in dump line are under study.

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Measurement:

position and energy deposit















#### Pixel Beam Profile Monitor for Linear Collider

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#### 1 Introduction

At linear colliders, it is expected that a large number of  $e^-e^+$  pairs are created by the QED process  $\gamma\gamma \to e^+e^-$  where  $\gamma$  may be off-shell or near-on-shell[1]. Depending on the number of off-shell photons involved, they are classified as Landau-Lifshitz (both off-shell), Bethe-Heitler (one of them is off-shell), and Breit-Wheeler (both near-on-shell). These pairs are predominantly created along the beamline, and acquires  $p_t$  kick by the electromagnetic field of the on-coming bunch. As long as the pair is relativistic and the direction is the same as the co-moving bunch, the net force due to the co-moving bunch  $\pm e(\vec{E} + \vec{\beta} \times \vec{B})$  cancels out ( $\vec{\beta}$  is the velocity of the pair particle in unit of c). One then only needs to consider the effect of the on-coming beam (Figure 1).

Typical parameters of the bunch is  $\sigma_x/\sigma_y/\sigma_z = 260 \text{nm}/3 \text{nm}/80 \mu\text{m}$ , and the number of particles per bunch N is  $\sim 10^{10}$ . If we assume a rectangular beam of  $2\sigma_x \times 2\sigma_y \times 2\sigma_z$  with uniform charge density and  $\sigma_y \ll \sigma_x$ , this creates

$$E(\text{dyne/esu}) = B(\text{gauss}) = \frac{\pi e N}{2\sigma_x \sigma_z} \sim 3.6 \times 10^7$$
(1)

just above or below the on-coming bunch in the laboratory frame. For the typical value of p = 300 MeV/c, the curvature due to both E and B fields is about  $170\mu\text{m}$  which can be compared to the bunch length of  $80\mu\text{m}$ . If the charge of the particle and the on-coming bunch are opposite sign, the created particle would undergo a number of oscillations around the beam plane and the net  $p_t$  acquired will be small. On the other hand, if the particle and the

### **Pixel Beam Profile Monitor**

H. Yamamoto et al., University of Hawaii



The sensor arrangement; the top side faces the IP.

readout chip pixel sensor

One 'segment' ; the bottom side faces the IP.



Schematic diagram of the 3D pixel concept

**3D Pixel** 1. Fast charge collection

< 1 nsec :bunch separation

2. Radiation hard >>50kRad/year,10<sup>7</sup>n/cm<sup>2</sup>/year

- 3. Flexible geometry
- 4. Active edge